


## Solar Photovoltaic Applications


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Mechanical Engineering 483  
**Alternative Energy Engineering II**

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## Outline


- Midterm exam results
- Meet on Wednesday at PPM  
Conference room for photovoltaic tour
- Photovoltaic basics
- Applications of photovoltaic systems
- Costs and cell efficiencies
- Conclusions



## Midterm Results

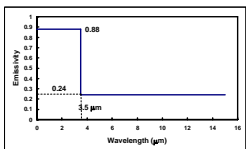
- Number of students: 30
- Maximum possible score: 90
- Mean: 43.8
- Median: **43**
- Standard Deviation: 15.4

10 18 23 24 31 32 32 34 34 37  
37 40 41 41 **42 44** 46 48 49 50  
51 52 54 54 56 58 58 67 69 81



## Midterm Problem One

- **Given:** Spectral emissivity
- **Find:** Solar radiation absorbed




$$\bar{\alpha}_{solar} = \bar{\epsilon}_{solar} = 0.88[f(\lambda T = 20,3200 \mu m \cdot K) - 0] + 0.24[1 - f(\lambda T = 20,300 \mu m \cdot K)]$$

$$= 0.88(0.9859 - 0) + 0.24(1 - 0.9859) = 0.8710$$

For 800 W/m<sup>2</sup> incoming solar radiation the absorbed radiation is (0.8710)(800 W/m<sup>2</sup>) = **696.8 W/m<sup>2</sup>**.

**b. If the surface is opaque, what happens to the radiation that is not absorbed?** It is reflected.



## Midterm Problem One II


**c. What is the emissive power of the surface if its temperature is 340 K?**

$$\bar{\alpha}_{340 K} = \bar{\epsilon}_{340 K} = 0.88[f(\lambda T = 1,190 \mu m \cdot K) - 0] + 0.24[1 - f(\lambda T = 1,190 \mu m \cdot K)]$$

$$= 0.88(0.00201 - 0) + 0.24(1 - 0.00201) = 0.2413$$

$$E = \bar{\epsilon}\sigma T^4 = (0.2413) \frac{5.6704 \times 10^{-8} W}{m^2 \cdot K^4} (340 K)^4 \quad \mathbf{E = 182.8 W/m^2}$$


**d. What is the total amount of radiant energy leaving the surface? It is sum of the emissive power, 182.8 W/m<sup>2</sup>, plus reflected energy, 800 W/m<sup>2</sup> - 696.8 W/m<sup>2</sup> = 103.2 W/m<sup>2</sup>. Total radiant energy leaving the surface is **286.1 W/m<sup>2</sup>**.**



## Midterm Problem Two

- **Given:** problem one surface is absorber plate in solar collector at 340 K. Glass plate has T = 320 K and  $\epsilon = 0.85$ .  $h_{gap} = 3.5 W/m^2 \cdot K$ .
- **Find:** heat transfer, per unit area between the absorber plate and the lower glass plate?

$$Q_{top} = h_{p-g2} A_c (T_p - T_{g2}) + \frac{A_c \sigma (T_p^4 - T_{g2}^4)}{\frac{1}{\epsilon_p} + \frac{1}{\epsilon_{g2}} - 1} \Rightarrow \frac{Q_{top}}{A_c} = \frac{3.5 W}{m^2 \cdot K} (340 K - 320 K)$$

$$+ \frac{5.6704 \times 10^{-8} W}{m^2 \cdot K^4} [(340 K)^4 - (320 K)^4] = \frac{107.8 W}{m^2}$$


### Midterm Problem Two II

- Is  $Q$  in part a less than, greater, than or equal to  $Q_{top}$ ? It is equal
- Find: heat transfer coefficient,  $U_{P-g2}$ , between the absorber plate and the lower glass plate?

$$U_{P-g2} = \frac{Q_{top}}{A_c(T_P - T_{g2})} = \frac{\frac{Q_{top}}{A_c}}{(T_P - T_{g2})} = \frac{\frac{107.8W}{m^2}}{(340K - 320K)} = 5.39W/m^2 \cdot K$$

- Is  $U_{P-g2}$  less than, greater, than or equal to  $U_{top}$ ? It is greater; it has the same heat flow,  $Q_{top}$ , with a smaller temperature difference

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### Midterm Problem Three

- Given: solar collector rating sheet.
- Find: efficiency for  $T_{in} = 40^\circ C$ ,  $I = 800 W/m^2$  and ambient temperature =  $20^\circ C$

$$\eta = 0.709 - 3.26090 \frac{P}{I} - 0.01203 \frac{P^2}{I} = 0.709 - 3.26090 \frac{20}{800} - 0.01203 \frac{20^2}{800} = 62.1\%$$

- Find:  $T_{out}$  for water using test flow rate from sheet and previous data

$$T_{out} = T_{in} + \frac{Q_u}{\dot{m}c_p} = T_{in} + \frac{\eta A_c}{\dot{m}c_p} = 40^\circ C + \frac{(62.1\%) \frac{800W}{m^2} (2.411m^2)}{\frac{48mL}{s} \frac{1000kg}{m^3} \frac{1J}{10^6mL \cdot kg \cdot ^\circ C}} = 46.1^\circ C$$

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### Midterm Problem Three II

- Find: fraction of 90 therms/month from collector for solar radiation =  $4 kWh/m^2/day$  for 30-day month with  $\tau\alpha/(\tau\alpha)_n = 0.94$ ,  $T_a = 17.8^\circ C$ , and  $F'_R/F_R = 0.97$ .
- $F_{R,U_c}$  = negative slope =  $3.975 W/m^2 \cdot ^\circ C$  and  $F_{R,U_c}(\tau\alpha)_n$  = intercept =  $0.715$ ; 90 therms/mo =  $(90 \times 10^9 \text{Btu/therm})(1.055 \text{ kJ/Btu})(GJ/10^9 \text{ kJ}) = 9.495 \text{ GJ/mo}$ .  $H_{total}$  = (30 days)  $(4 \text{ kWh/m}^2/day) (0.0036 \text{ GJ/kWh}) = 0.432 \text{ GJ/m}^2/month$ .  $F_{R,U_c} = (3.975 \text{ W/m}^2 \cdot ^\circ C)(10^{-9} \text{ GJ/W} \cdot \text{s})(3600 \text{ s/hr})(24 \text{ hr/day})(30 \text{ days/mo}) = 0.01030 \text{ GJ/m}^2/mo$ ,

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### Midterm Problem Three III

$$X = A_c \left[ F_{R,U_c} \frac{F'_R \Delta t}{F_R D} (T_{ref} - T_a) \right] = (2.411m^2) \left[ \frac{0.01030GJ}{m^2 \cdot mo} (0.97) \frac{mo}{9.495GJ} (100^\circ C - 17.8^\circ C) \right] = 0.2086$$

$$Y = A_c \left[ F_{R,U_c} (\tau\alpha)_n \frac{F'_R \tau\alpha}{F_R (\tau\alpha)_n} \frac{H_{total}}{D} \right] = (2.411m^2) \left[ (0.715)(0.97)(0.94) \frac{0.432GJ}{9.495GJ} \right] = 0.0715$$

- $f = 1.029Y - 0.065X - 0.245Y^2 + 0.0018X^2 + 0.0215Y^3 = 1.029(0.0715) - 0.065(0.2086) - 0.245(0.0715)^2 + 0.0018(0.2086)^2 + 0.0215(0.0715)^3 = 5.89\%$  of the monthly heating load is supplied by solar

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### Wednesday Class Meeting

- Meet in PPM Conference room
- Entrance from Lot C6
- Near corner of Halsted and Etiwanda

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### Photovoltaics

A. Hunter Fanney  
Heat Transfer & Alternative Energy Systems Group  
National Institute of Standards and Technology




January 26, 2007

Slides with NIST logo shown here taken from this presentation

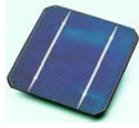


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### Photovoltaic Terminology

- CELL - basic building block in factory
- MODULE - smallest unit that can do real-world work; building block in the field
- ARRAY - electrically interconnected modules
  - Series Wired to Increase Voltage
  - Parallel Wired to Increase Current

### Cells in Modules in Arrays


- Solar cell 
- Solar module 
- Solar array 



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### Basic Concepts


- Direct conversion of light energy into electrical current
- Based on adsorption of light photon with energy  $E = h\nu = hc/\lambda$ 
  - Planck's constant:  $h = 6.62607 \times 10^{-23}$  J-s
  - Light speed:  $c = 299,792,458$  m/s
  - frequency( $s^{-1}$ ) =  $\nu$  wavelength (m) =  $\lambda$
- $E = h\nu$  also basis for spectrum of blackbody radiation



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### Semiconductors


- Conductors have lots of free electrons to conduct heat and electricity
- Insulators have almost no free electrons
- Pure semiconductors can produce some free electrons leaving electron-deficient atoms known as holes
- Doped semiconductors add materials with different number of valence electrons



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### Semiconductors II


- Silicon has 4 electrons in valence band
- Adding phosphorus with 5 electrons in its valence band makes it easier for the doped material to release free electrons
  - This is called an n-type material
- Adding aluminum with 3 electrons in its valence band makes it easier for the doped material to produce holes
  - This is called a p-type material



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### Semiconductors III

- Joining n-type and p-type materials results in a pn junction
- Electrons and holes flow across junction to rejoin
- External circuit is more efficient mechanism for electrons to rejoin holes
- Solar cell is pn junction where photons provide energy for electrons to become free electrons



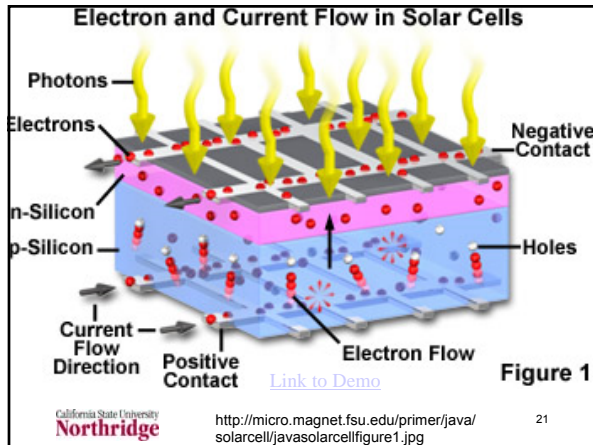
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### Semiconductors to Solar Cells

- Physics of solids visualizes valance band where electrons are linked to atom and conduction band for free electrons
- Free electrons have higher energy
- Band gap is energy difference between valance band and conduction band
- Photon from sunlight must have enough energy to move electron from valance to conduction band

### Silicon Band Gap = 1.11 eV

- $E = 1.11 \text{ eV} = hc/\lambda$  gives  $\lambda = 1.12 \mu\text{m}$
- Less energetic photons ( $\lambda > 1.12 \mu\text{m}$ ) will not release an electron
- Higher energy photons ( $\lambda < 1.12 \mu\text{m}$ ) will release electron and produce heat
- Radiant energy not releasing electron will be reflected or absorbed
- For  $\lambda T \leq (1.12 \mu\text{m})(5800 \text{ K}) = 6578.45 \mu\text{m}\cdot\text{K}$  solar fraction is 77.5% (not all used)



### Solar Cell Current Density

$$J_L = J_s + J_o - J_o e^{\frac{e_0 V}{kT}}$$

- See Hodge pp 231-232 for derivation
  - Current density  $J_L = I_L/A$  delivered to load
  - Internal current densities across p-n junction: p-to-n,  $J_o$ , and n-to-p,  $J_r$ , net  $J_j = J_r - J_o$
  - Cell output current density  $J_s$ ;  $J_L = J_s - J_j$
  - $e_0$  = electron charge =  $1.60218 \times 10^{-19} \text{ J/V}$
  - $k$  = Boltzmann's constant =  $1.381 \times 10^{-23} \text{ J/K}$
  - $V$  = cell voltage

### Solar Cell Output

- $J_L = 0$  gives open circuit voltage

$$J_L = J_s + J_o - J_o e^{\frac{e_0 V}{kT}} = 0 \Rightarrow V_{oc} = \frac{kT}{e_0} \left( \frac{J_s}{J_o} - 1 \right)$$

- $V = 0$  gives short circuit current

$$J_L = J_s + J_o - J_o e^{\frac{e_0 \cdot 0}{kT}} = J_s + J_o - J_o = J_s$$

$$J_L = J_s + J_o - J_o e^{\frac{e_0 V}{kT}} \Rightarrow \frac{J_L}{J_s} = 1 + \frac{J_o}{J_s} - \frac{J_o}{J_s} e^{\frac{e_0 V}{kT}}$$

### Solar Cell Output II

- For given open circuit voltage,  $e_0$  and temperature,  $T$ , find  $J_o/J_s$

$$= \frac{kT}{e_0} \left( \frac{J_s}{J_o} - 1 \right) \Rightarrow \frac{J_o}{J_s} = \frac{1}{\frac{e_0 V_{oc}}{kT} + 1}$$

- Use this  $J_o/J_s$  to plot  $J_L/J_s$  versus  $V$

$$\frac{J_L}{J_s} = 1 - \frac{J_o}{J_s} \left[ e^{\frac{e_0 V}{kT}} - 1 \right] = 1 - \frac{e^{\frac{e_0 V}{kT}} - 1}{\frac{e_0 V_{oc}}{kT} + 1}$$

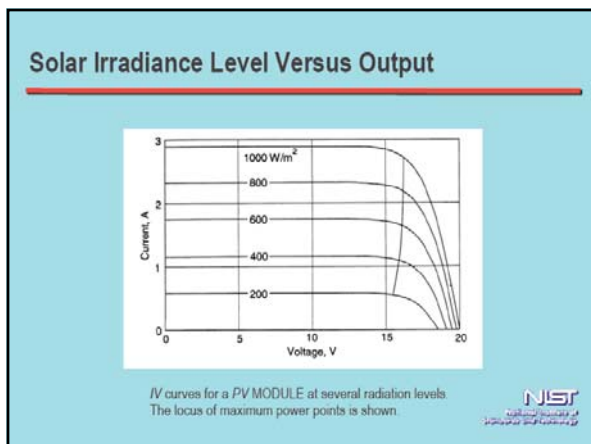
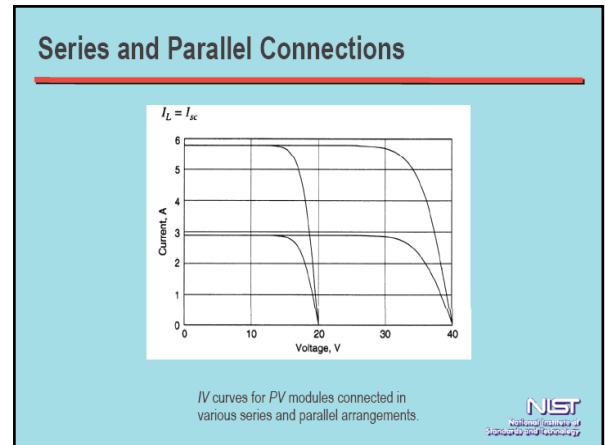
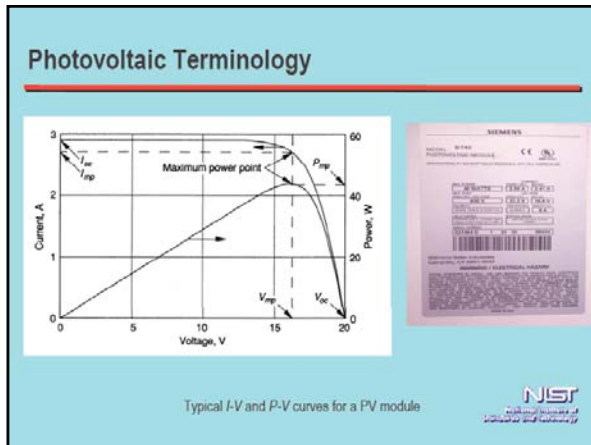
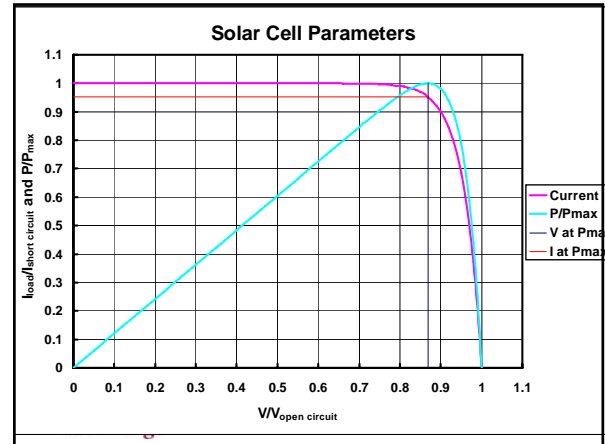
### Solar Cell Power

- $P = I_L V = J_L A V$
- $P = J_L A V = J_s A V \frac{J_L}{J_s} = J_s A V \left( 1 - \frac{e_0 V}{kT} - 1 \right)$
- $dP/dV = 0$  gives  $P_{max}$

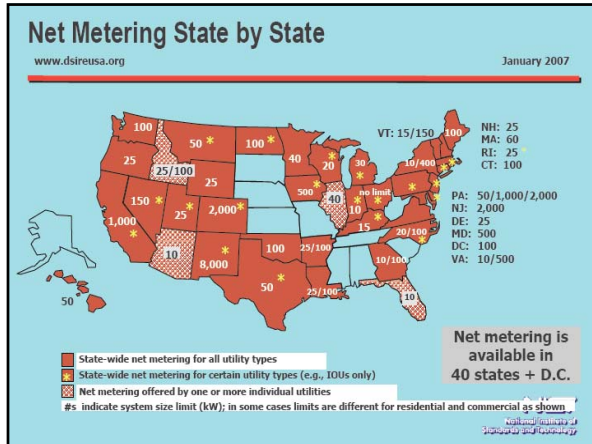
$$\frac{dP}{dV} = J_s A \left( 1 - \frac{e_0 V}{kT} - 1 \right) + J_s A V \left( \frac{e_0}{kT} \right) = J_s A \left( \frac{e_0 V_{oc}}{kT} + 1 - e^{\frac{e_0 V}{kT}} + 1 + \frac{e_0 V}{kT} e^{\frac{e_0 V}{kT}} \right)$$

$$\frac{dP}{dV} = 0 \Rightarrow 2 + e^{\frac{e_0 V_{oc}}{kT}} + e^{\frac{e_0 V_{Pmax}}{kT}} \left( \frac{e_0 V_{Pmax}}{kT} - 1 \right) = 0 \quad \text{Solve numerically for } V_{Pmax} = V \text{ at } P_{max}$$

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### Grid Interconnected Systems



### Conversion Efficiency

$$\eta_c = \frac{\int_0^{\tau} P_o d\tau}{A \int_0^{\tau} H_T d\tau}$$

where  
 A is a representative area, m<sup>2</sup>,  
 H<sub>T</sub> is the incident solar radiation, W/m<sup>2</sup>,  
 P<sub>o</sub> is the panels electrical power output, W  
 and τ is the time interval selected for monitoring, h.

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### Photovoltaic Technologies

Conventional - 94% of Market     Thin Film - 6% of Market

Material	Laboratory Cell Efficiency	Laboratory Module Efficiency
Crystalline Silicon	24.7%	23%
Multi Crystalline Silicon	20.3%	15.3%
ClGS	18.8%	13.4%
CdTe	16.5%	10.7%

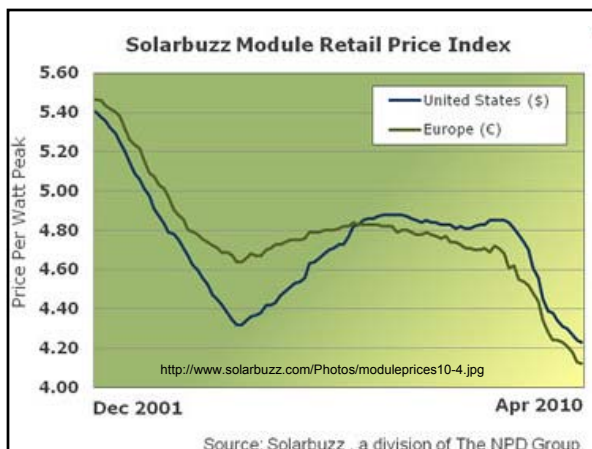
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### The Photovoltaic Industry

- Worldwide PV Shipments
  - 1988 - \$1.5 billion
  - 2020 - \$27 billion
- Price History
  - 1959 - \$1000 per Watt
  - 1973 - \$100 per Watt
  - 1980 - \$10 per Watt
  - 12/06 - \$5.47 per Watt

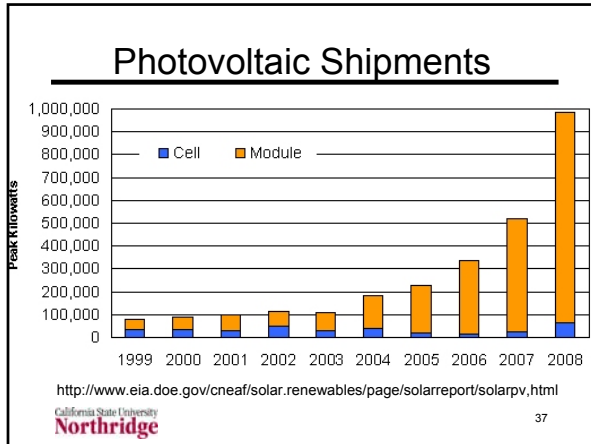
PV Growth Strategy 2000-2020  
 PV Technology Roadmap Workshop, 6/99

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### Photovoltaic Industry

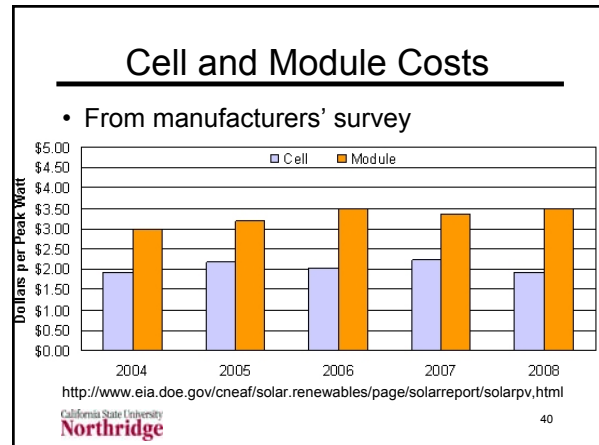
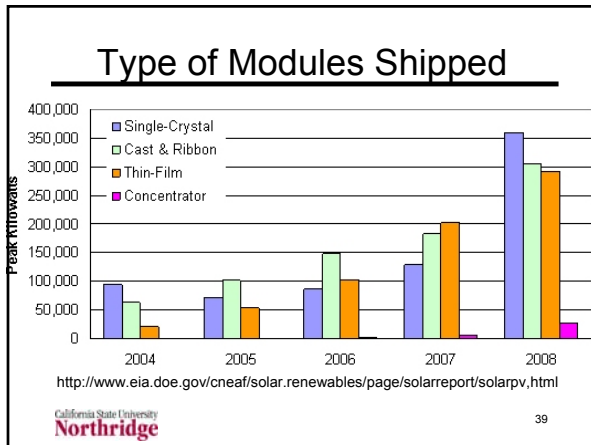
- PV Manufacturers and Technologies
  - Single-Crystalline - SolarWorld, Sun Power (Back Contact)
  - Polycrystalline - BP Solar, Sharp, Kyocera Solar, Mitsubishi, GE
  - Polycrystalline String Ribbon - ASE Americas, Evergreen Solar
  - Silicon Film - General Electric
  - Amorphous Silicon - United Solar Ovonic Corporation
  - Cadmium Telluride - First Solar
  - Copper Indium Diselenide/Copper Indium Gallium Diselenide - Wurth Solar, Global Solar, Shell Solar



### Module Types

- Crystalline silicon from a wedge of single-crystal or polycrystalline silicon
  - Cast, thin-film, or ribbon
- Thin-film from layers of semiconductor material, such as amorphous silicon (a-Si), cadmium telluride (CdTe), or copper indium gallium selenide (CIGS)
- Concentrator uses lenses that gather and concentrate sunlight onto the cell

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### DOE's Solar America Initiative Program Goals

Market Sector	Current Market Price	PV Generated 2005	PV Generated 2010	PV Generated 2015
Residential	5.8 - 16.7	23-32	13-18	8-10
Commercial	5.4 - 15.0	16-22	9-12	6-8

Prices are cents per kWh  
Current prices based on electric generation with conventional sources  
Market goals based on grid-tied sources

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### Photovoltaic Economics

Payback Time  
non-leases, 5% discount rate, varying system prices

**PV Incentives**  
30% Federal Tax Credit

- Maryland - Lesser of 20% or \$3K Grant
- Germany - Rebate of \$0.54 per kWh declining at 5% per year

**Example**  
2000 Watt System in Maryland  
2000 watt @ \$9/watt = \$18,000  
Less \$5,000 Tax Credit, Less \$3,000  
Net Cost 10K or \$5/watt

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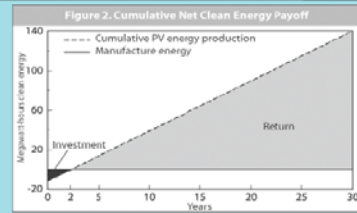
### SF Valley Photovoltaic Costs

- From [www.findsolar.com](http://www.findsolar.com)
- Supply 25% of average 860 kWh/mo
- 1.49 kW (peak) – 148 ft<sup>2</sup> area
- Cost \$10,416 (\$2,531 after incentives)  
– \$7000/kW(peak) for entire system
- Savings \$22/month, \$10,995 for 25 years with 4%/year cost increase
- Return on investment = 9.3% with incentives, –3.24% without incentives

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### Photovoltaic Energy Payback and Avoided Emissions

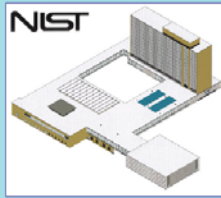


- A PV system that meets 50% of average household use would
  - Eliminate 0.5 tons of SO<sub>2</sub> and 0.3 tons of NO<sub>x</sub>
  - CO<sub>2</sub> emissions avoided would offset the operation of two cars for 28 years

Source- What is the Energy Payback for PV? DOE's National Center for Photovoltaics

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### NIST Administration Building's PV System



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### NIST Administration Building's PV System



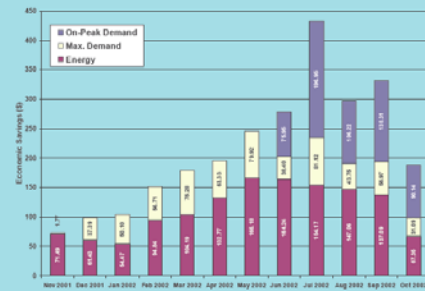
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### NIST Administration Building's PV System



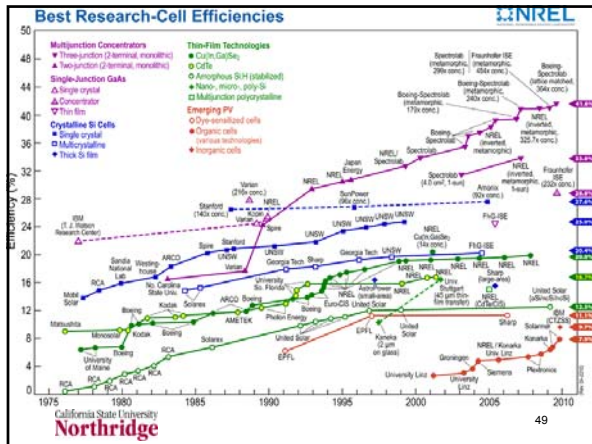
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### NIST Administration Building's PV System



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### Is Efficiency Important?

- Yes and no
- Solar energy is free
- What is cost per square meter of solar photovoltaic cell?
  - Solar cell costs most expensive
    - Low efficiency, low cost could be better
  - Auxiliary costs for structure
    - High efficiency will always be better here

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### Organic Photovoltaic

- $\eta < 6\%$
- Lower cost than Silicon
- Lifetime a few 1000 hours
- Goals: 10% and 10,000 h

Transparent protective layers, ~2 mm

Polymer-fullerene mixture, 100-200 nm

Electrode, ~100 nm

http://www.robad.com/wp-content/gallery/cache/198\_400x300\_nist-organic-photovoltaics.jpg

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### Solar Conclusions

- Promise of large amounts of pollution-free energy with significant limitations
  - Low energy flux requires large area
  - Costs for current solar materials are not justified by cost savings
  - Solar peak matches electricity demand and thermal storage extends generation time
  - Science of solar energy well understood, but problems with pervious commercial
  - Still need significant cost reductions to make solar PV cost effective

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